



Fig. 2 Rectified ion transport through 2D nanofluidic heterostructures. (a) Representative current–voltage responses of the SP-modified (circle) and unmodified GOM (square) in 10 mM KCl, pH = 3.0. (b) The ionic current rectification (ICR) ratio and the ionic conductance of the SP-GOM and the GOM are summarized. The asymmetric modification of SP generates rectified transmembrane ion transport, but its influence to the total ionic conductance is very limited. (c) The ICR ratio is controlled by the concentration of SP in the drop-casting process. The concentration of SP for the modification in (a) and (b) is 0.6 mg ml^{-1} .

droplet (0.6 mg ml^{-1}), the N/C atomic ratio increases to about 1.15% on the top surface, and rapidly decays to the level of the unmodified GOM within the uppermost 100–150 nm (Fig. 1e, S4 and S5†). Parallel XPS depth profiling from the bottom of the SP-GOM shows that the nitrogen content there stays at the

background level. The penetration depth of the SP moieties depends on the concentration of SP in the drop-casting process (Fig. 1f). The attached SP molecules do not further penetrate into the membrane after being soaked in water for hours (Fig. S6†).

The formation of the asymmetric membrane structure results in rectified ion transport through the SP-GOM. A piece of the SP-GOM was mounted in a two-compartment photo-electrochemical cell, filled with potassium chloride solution (10 mM, pH = 3.0, Fig. S7†). As typically shown in Fig. 2a, the diode-like current–voltage response is recorded with an ICR ratio of about 4.6. The concentration of SP for the chemical modification is 0.6 mg ml^{-1} . In contrast, the unmodified GOM exhibits a nearly linear ion transport behavior. Besides the asymmetric membrane structure, small amounts of SP moieties may present an open-ring structure in an acidic environment,³⁰ which also accounts for the observed ICR effect. The asymmetric modification of SP generates rectified ion transport through the entire membrane,^{31,32} but it has a very limited influence on the total ionic conductance (Fig. 2b, and S8 and S9†). By increasing the concentration of SP in the drop-casting process, the ICR ratio of the SP-GOMs can be gradually enhanced (Fig. 2c).

Upon UV irradiation (wavelength of 365 nm), the SP-GOM can be excited to a highly rectifying state (Fig. 3a and b). Meanwhile, under the irradiation of visible light (wavelength of 520 nm), the UV-activated ionic current rectification can be perfectly retrieved to the initial state (the resting state) with low rectification. Fig. 3c shows the UV-vis spectra of SP in solution. An absorption maximum at 420-nm is observed after UV irradiation indicating the photoisomerization from the neutral SP state to the cationic merocyanine (MCH^+) state.³³ In this process, the spiropyran molecules open the pyran bond and transform to the zwitterionic merocyanine (MC). In acidic solution, the protonation of the phenolate anion yields the cationic MCH^+ .³⁰ This transformation can be visualized by the photochromic reaction in an acidic SP solution (Fig. S10 and S11†).³⁴ Additionally, the GO nanosheets remain negatively charged with a surface potential below -30 mV in acidic solution, down to pH = 3.0 (Fig. S12†). Therefore, the presence of cationic MCH^+ contributes positive charges and alters the overall charge density in the surface layers, forming charged heterostructures with the beneath unmodified GO nanochannels (Fig. 3a), that account for the photo-enhanced ionic rectification.³⁵ Upon the irradiation of visible light, MCH^+ can be reversibly converted back to the SP isomer, yielding a fully photo-switchable ionic diode (Fig. S11b†). The photo-induced reversible change in the surface charge properties can also be supported by the zeta potential measurements of the SP modified GO nanosheets (SP-GO) in solution. Upon UV light irradiation, a remarkable positive shift in the zeta potential is found in SP-GO (Fig. S13†), and upon visible light irradiation, the zeta potential drops back to the initial level.

We systematically investigated the time evolution of the current–voltage response of the SP-GOM under UV irradiation. The ICR ratio gradually increases with prolonged illumination time (Fig. 4a). A 58.3% increase in the ICR ratio is found within





Fig. 3 The photo-switchable 2D nanofluidic diode. (a) Top: current–voltage responses of the SP-GOM before and after irradiation with light of different wavelengths (UV light, 365 nm and visible light, 520 nm). The UV irradiation excites the SP-GOM to a highly rectifying state, and the visible light irradiation perfectly retrieves it to the initial resting state. Bottom: schematic illustration of the photo-induced changes in the molecular and charge state in the multi-layers of the SP-GOM, corresponding to the above current–voltage responses. The ICR ratios are summarized in (b). (c) UV-vis spectra of SP in solution. Upon UV irradiation, an absorption peak at 420 nm is observed (red), indicating the photoisomerization from SP to MCH⁺. This transformation can be fully retrieved under the irradiation of visible light (blue).

about 5 minutes and a more than 10-fold increment is achieved within 20 minutes. This trend can be supported by the accumulated photoisomerization of the SP molecules in bulk solution. The amount of cationic MCH⁺ is gradually increased with the duration of UV illumination (Fig. S11a[†]). A maximum ICR ratio of about 48 is achieved. Although this value is not too high compared to previously reported 1D nanofluidic systems,³⁶ to the best of our knowledge, it is the best value obtained in existing 2D nanofluidic systems.^{37–42} Moreover, the response rate of the SP-GOM is very fast, compared to other responsive nanofluidic systems.^{43–45}

The SP-GOM can be reversibly switched between high- and low-rectifying states for many cycles (Fig. 4b). In each cycle, the UV (365 nm) or the visible light (520 nm) irradiation was maintained for 300 seconds. In contrast, the unmodified GOMs stay in a non-rectifying state regardless of the light irradiation. The photo-responsiveness of the SP-GOM is robust. No evident decline in reversibility is found for more than 20 cycles.

Conclusions

In conclusion, for the first time, we integrate light-responsiveness and ionic rectifying functions into a 2D

nanofluidic system. The membrane-scale 2D nanofluidic diodes can be reversibly and rapidly switching between high- and low-rectifying states, controlled by light irradiation. The structural and photo-induced charge heterostructures collaboratively result in a prominently enhanced ionic rectification. The maximum ICR ratio of 48 is the best value achieved in existing 2D nanofluidic systems. The bottom-up assembly and asymmetric drop-casting modification provide a facile and general strategy for building smart 2D nanofluidic devices and materials with versatile responsibilities and asymmetric ion transport characteristics for potential applications in energy, environment, sensing, and healthcare related fields.

Experimental section

Membrane fabrication and chemical modification

The GOMs were prepared by the vacuum filtration of 40 ml of a GO dispersion (1.0 mg ml⁻¹) through a mixed cellulose ester membrane (47 mm in diameter, effective pore size of 0.1 μm). To stabilize the hydrophilic GOMs, they were heated at 80 °C for 24 hours in an oven before use. 6.0 mg of 1-(2-hydroxyethyl)-3, 3-dimethylindolino-6'-nitrobenzopyrrolospiran (SP) was dissolved in 10 ml of ethanol. To obtain the SP-GOM, a droplet of SP



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